

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard J. Olmer, et al

Art Unit: 1746

Serial No.: 10/675,575

Examiner: El Arini, Zeinab

Filed: 09/30/2003

Confirmation No.: 9967

Attorney Docket No.: Bevers 2-3-16-20/075903-81

For: In-Situ Removal of Surface Impurities Prior to Arsenic-Doped Polysilicon  
Deposition in the Fabrication of a Heterojunction Bipolar Transistor

PROPOSED AMENDMENT UNDER 37 C.F.R. 116

June 7, 2006

BY FACSIMILE TRANSMISSION TO 571-273-8300

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir or Madam:

In response to the final Office Action mailed on April 12, 2006, entry of the claim amendments set forth herein is respectfully requested under the provisions of 37 C.F.R. 116.

RECEIVED  
CENTRAL FAX CENTER  
JUN 07 2006

Do not enter  
ZE 6/25/06